GENERAL DESCRIPTION

Passivated, sensitive gate triacs in a full pack plastic envelope, intended for use in general purpose bidirectional switching and phase control applications. These devices are intended to be interfaced directly to microcontrollers, logic integrated circuits and other low power gate trigger circuits.

PINNING - SOT186A

PIN	DESCRIPTION			
1	main terminal 1			
2	main terminal 2			
3	gate			
case	isolated			

QUICK REFERENCE DATA

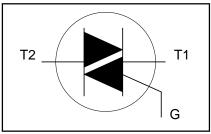
SYMBOL	PARAMETER	MAX.	UNIT
V _{drm} I _{t(rms)} I _{tsm}	BT136X- Repetitive peak off-state voltages RMS on-state current Non-repetitive peak on-state current	600D 600 4 25	V A A

PIN CONFIGURATION

case

0

SYMBOL



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{drm}	Repetitive peak off-state voltages		-	-600 600	V
I _{T(RMS)} I _{TSM}	RMS on-state current Non-repetitive peak on-state current	full sine wave; $T_{hs} \le 92 \degree C$ full sine wave; $T_j = 25 \degree C$ prior to surge	-	4	А
		t = 20 ms	-	25 27	A A
l²t dl _⊤ /dt	I ² t for fusing Repetitive rate of rise of on-state current after	t = 16.7 ms t = 10 ms $I_{TM} = 6 A; I_G = 0.2 A;$ $dI_C/dt = 0.2 A/\mu s$	-	3.1	A A ² s
	triggering	T2+ G+ T2+ G- T2- G- T2- G+	-	50 50 50 10	A/μs A/μs A/μs A/μs
I _{GM} V _{GM} P _{GM}	Peak gate current Peak gate voltage Peak gate power		-	2 5 5	À V W
P _{G(AV)} T _{stg} T _j	Average gate power Storage temperature Operating junction temperature	over any 20 ms period	-40 -	0.5 150 125	° ℃ Ŵ

Triacs		
logic level		

BT136X series D

ISOLATION LIMITING VALUE & CHARACTERISTIC

 $T_{hs} = 25$ °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _{isol}	R.M.S. isolation voltage from all three terminals to external heatsink	f = 50-60 Hz; sinusoidal waveform; R.H. \leq 65% ; clean and dustfree	-	-	2500	V
C _{isol}	Capacitance from T2 to external heatsink	f = 1 MHz	-	10	-	pF

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R _{th j-hs} R _{th j-a}	Thermal resistance junction to heatsink Thermal resistance junction to ambient	full or half cycle with heatsink compound without heatsink compound in free air		- - 55	5.5 7.2 -	K/W K/W K/W

STATIC CHARACTERISTICS

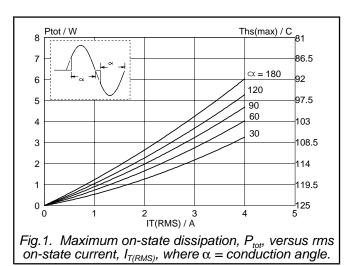
 $T_i = 25$ °C unless otherwise stated

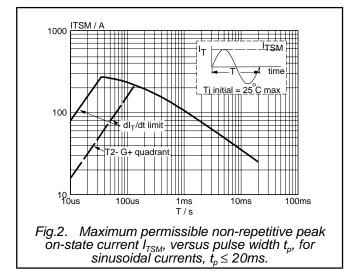
SYMBOL	PARAMETER	CONDITIONS		MIN.	TYP.	MAX.	UNIT
I _{GT}	Gate trigger current	$V_{\rm D} = 12 \text{ V}; I_{\rm T} = 0.1 \text{ A}$					
01			2+ G+	-	2.0	5	mA
		Т Т	2+G-	-	2.5	5	mA
		Т Т	2-G-	-	2.5	5	mA
			2- G+	-	5.0	10	mA
	Latching current	$V_{\rm D} = 12 \text{ V}; I_{\rm GT} = 0.1 \text{ A}$					
	-	T	2+G+	-	1.6	10	mA
		-	2+G-	-	4.5	15	mA
			2-G-	-	1.2	10	mA
			2- G+	-	2.2	15	mA
I _H	Holding current	$V_{\rm D} = 12 \text{ V}; I_{\rm GT} = 0.1 \text{ A}$		-	1.2	10	mA
I _H V⊤	On-state voltage	$I_T = 5 A$		-	1.4	1.70	V
V _{GT}	Gate trigger voltage	$V_{\rm D} = 12 \text{ V}; I_{\rm T} = 0.1 \text{ A}$		-	0.7	1.5	V
		$ V_{D} = 400 V; I_{T} = 0.1 A; T_{i} = 125 °C$)	0.25	0.4	-	V
I _D	Off-state leakage current	$V_{D} = 400 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T}_{j} = 125 \text{ °C}$ $V_{D} = V_{DRM(max)}; \text{ T}_{j} = 125 \text{ °C}$		-	0.1	0.5	mA

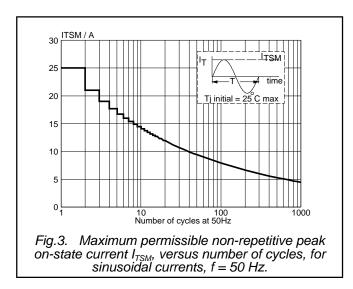
DYNAMIC CHARACTERISTICS

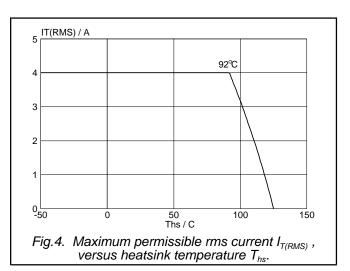
 $T_j = 25$ °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
dV _D /dt	Critical rate of rise of off-state voltage	$V_{DM} = 67\% V_{DRM(max)}; T_j = 125 °C;$ exponential waveform; $R_{GK} = 1 k\Omega$	-	5	-	V/μs
t _{gt}		$I_{TM} = 6 \text{ A}; V_D = V_{DRM(max)}; I_G = 0.1 \text{ A}; $ $dI_G/dt = 5 \text{ A}/\mu\text{s}$	-	2	-	μs









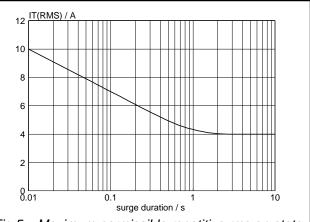
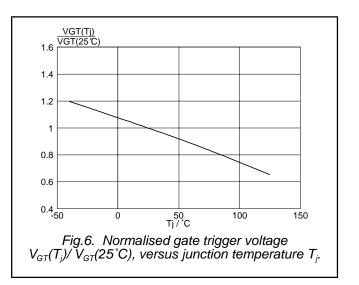
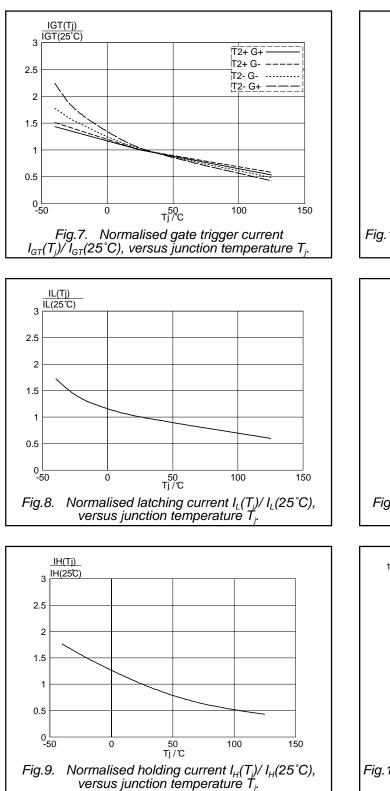
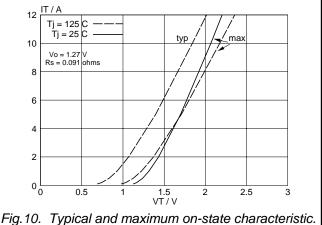
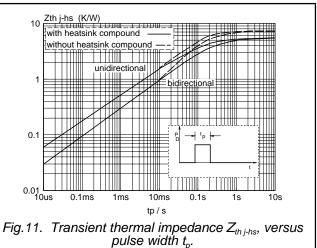


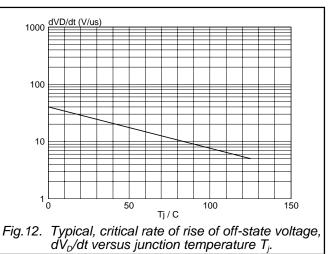
Fig.5. Maximum permissible repetitive rms on-state current $I_{T(RMS)}$, versus surge duration, for sinusoidal currents, f = 50 Hz; $T_{hs} \le 92$ °C.





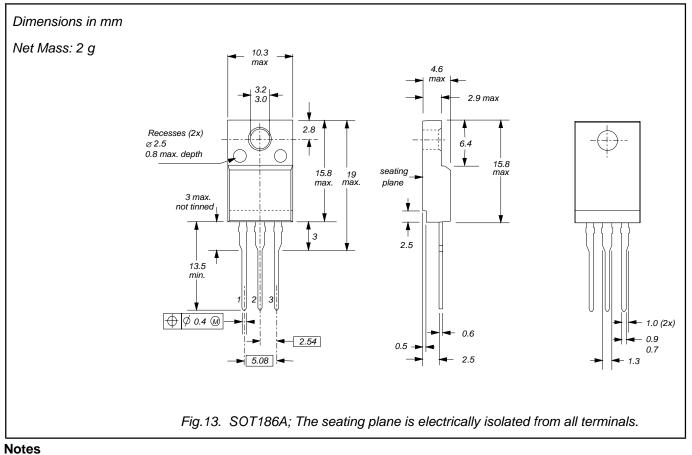






BT136X series D

MECHANICAL DATA



Refer to mounting instructions for F-pack envelopes.
Epoxy meets UL94 V0 at 1/8".

June 2001

Triacs logic level

DEFINITIONS

DATA SHEET STA	DATA SHEET STATUS					
DATA SHEET STATUS ¹	PRODUCT STATUS ²	DEFINITIONS				
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice				
Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in ordere to improve the design and supply the best possible product				
Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Changes will be communicated according to the Customer Product/Process Change Notification (CPCN) procedure SNW-SQ-650A				
Limiting values	·	·				

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

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